

Revision 0.91

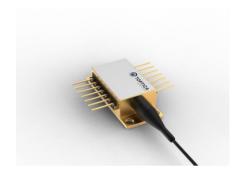
2024-04-11

## SINGLE FREQUENCY LASER DFB Laser



	Information

Product	Application
852 nm DFB Laser	Spectroscopy (Cs D2 line)
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	
with PM Fiber, integrated μ-Isolator and Angled Physical Contact (APC)	



#### Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	$T_C$	° C	-15		70
Operational Temperature at Chip	$T_{chip}$	° C	10		50
Forward Current	I <sub>F</sub>	mA			250
Reverse Voltage	$V_{R}$	V			2
Output Power	$P_{opt}$	mW			20
TEC Current	I <sub>TEC</sub>	Α			1,4
TEC Voltage	$V_{TEC}$	V			4,8

#### Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

#### **Recommended Operational Conditions**

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T <sub>case</sub>	° C	5		60
Operational Temperature at Chip	$T_{chip}$	° C	15		45
Forward Current	I <sub>F</sub>				230
Output Power	$P_{opt}$	mW	5		15

Measurement Conditions / Comments	
measured by integrated Thermistor	_
, ,	

### Characteristics Tchip = 25° at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	851	852	853
Target Wavelength	$\lambda_{\mathrm{T}}$	nm		852.347	
Linewidth	Δλ	MHz		0,6	1
Mode-hop free Tuning Range	$\Delta \lambda_{tune}$	pm	25	0	
Sidemode Suppression Ratio	SMSR	dB	30	45	
Temp. Coefficient of Wavelength	$d\lambda/dT$	nm/K		0,06	
Current Coefficient of Wavelength	dλ / dl	nm/mA		0,003	

eached within To	chip = 15 ° 45° C at 15 mW
Popt = 15 mW	
> 10 GHz, at targ	et wavelength
Popt = 15 mW	



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Characteristics	s Tchip = 25° at BOL				
Parameter	Symbol	Unit	min	typ	max
Laser Current	I <sub>LD</sub>	mA			230
Slope Efficiency	η	mW/mA		0,08	
Threshold Current	I <sub>th</sub>	mA			70
Polarization Extinction Ratio	PER	dB		20	

Measurement Conditions / Comments	
Popt = 15 mW	

Monitor Diode				
Parameter	Symbol Unit	min	typ	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>op</sub> μΑ/mV	/ 10		200

Measurement Conditions / Comments
5 V reverse voltage

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	Α		0,4	
Voltage	$U_TEC$	V		1,5	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		0,5	
Temperature Difference	ΔΤ	K			45

Measurement Conditions / Comments
Popt = 15 mW, ΔT =30 K
Popt =15 mW, ΔT =30 K
Popt = 15 mW, ΔT =30 K
15 mW, ΔT =  Tcase - Tchip

Thermistor	(Ctandard	NITC Tunch
nemisio	(2)3110310	NIC IVOE

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	Α		1.	1293 x 10 <sup>-</sup>	- 3
Steinhart & Hart Coefficient B	В		2.	3410 x 10	- 4
Steinhart & Hart Coefficient C	С		8.	7755 x 10 <sup>-</sup>	- 8

Measurement Conditions / Comments		
Tchip = 25° C		
$R_1/R_2$ = $e^{\Lambda}\beta(1/T_1$ - $1/T_2)$ at Tchip = $0^{\circ}$ $50^{\circ}$ C		



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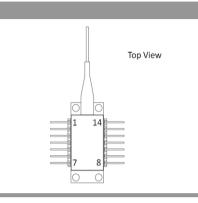
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## SINGLE FREQUENCY LASER DFB Laser



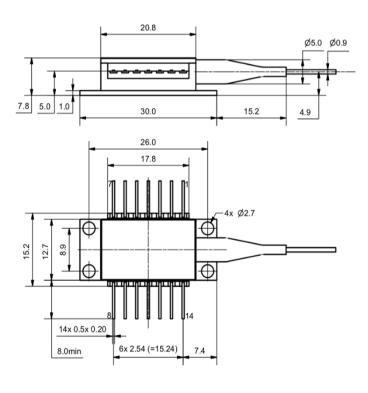
Pin Assignment			
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor	13	Case
3	Photo Diode Anode	12	not connected
4	Photo Diode Cathode	11	Laser Diode Cathode
5	Thermistor	10	Laser Diode Anode
6	not connected	9	not connected

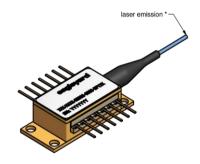
8 not connected



### Package Drawings

7 not connected





AIZ-16-0222-1415



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# SINGLE FREQUENCY LASER DFB Laser



Fiber and Connector Type (Output)		
Parameter		Measurement Conditions / Comments
PM Fiber	900 / 125 / 5.5 $\mu$ m, UV/Polyester-elastomer Coating (I = 1 +/-0.1 m)	
Connector	FC/APC (narrow key / 2mm)	

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## SINGLE FREQUENCY LASER DFB Laser

#### **Unpacking, Installation and Laser Safety**

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



A laser diode is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.



INVISIBLE LASER RADIATION

AVOID EYE OR SKIN EXPOSUR
TO DIRECT OR SCATTERED RADIATION CLASS

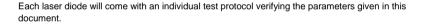
4 LASER PRODUCT

WAVELENGTH 852 nm

MAX. OUTPUT POWER 20 mW

IEC-60825-

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.







Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.